

DG9425EDQ-T1-GE3 Datasheet

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DiGi Electronics Part Number DG9425EDQ-T1-GE3-DG

Manufacturer Vishay Siliconix

Manufacturer Product Number DG9425EDQ-T1-GE3

Description IC SWITCH SPST-NCX4 30HM 16TSSOP

Detailed Description 4 Circuit IC Switch 1:1 30hm 16-TSSOP



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Purchase and inquiry

Manufacturer Product Number:Manufacturer:DG9425EDQ-T1-GE3Vishay SiliconixSeries:Product Status:-ActiveSwitch Circuit:Multiplexer/Demultiplexer Circuit:SPST - NC1:1Number of Circuits:On-State Resistance (Max):430hmChannel-to-Channel Matching (ΔRon):Voltage - Supply, Single (V+):-3V ~ 16VVoltage - Supply, Dual (V±):Switch Time (Ton, Toff) (Max):±3V ~ 8V51ns, 35ns-3db Bandwidth:Charge Injection:-38pCChannel Capacitance (CS(off), CD(off)):Current - Leakage (IS(off)) (Max):49pF, 37pF1nACrosstalk:Operating Temperature:-77dB @ 1MHz-40°C ~ 85°C (TA)Mounting Type:Package / Case:Surface Mount16-TSSOP (0.173°, 4.40mm Width)Supplier Device Package:Base Product Number:16-TSSOPDG9425		
Series:Product Status:-ActiveSwitch Circuit:Multiplexer/Demultiplexer Circuit:SPST - NC1:1Number of Circuits:On-State Resistance (Max):430hmChannel-to-Channel Matching (ΔRon):Voltage - Supply, Single (V+):-3V ~ 16VVoltage - Supply, Dual (V±):Switch Time (Ton, Toff) (Max):±3V ~ 8V51ns, 35ns-3db Bandwidth:Charge Injection:-38pCChannel Capacitance (CS(off), CD(off)):Current - Leakage (IS(off)) (Max):49pF, 37pF1nACrosstalk:Operating Temperature:-77dB @ 1MHz-40°C ~ 85°C (TA)Mounting Type:Package / Case:Surface Mount16-TSSOP (0.173", 4.40mm Width)Supplier Device Package:Base Product Number:	Manufacturer Product Number:	Manufacturer:
Active Switch Circuit: SPST - NC Substance (Max): 1:1 Number of Circuits: On-State Resistance (Max): 4 Voltage - Supply, Single (V+): - 3V - 16V Voltage - Supply, Dual (V±): \$\frac{2}{3}\text{V} - 8V -3db Bandwidth: Channel Capacitance (CS(off), CD(off)): Channel Capacitance (CS(off), CD(off)): Channel Capacitance (CS(off), CD(off)): 49pF, 37pF 1nA Crosstalk: -77dB @ 1MHz Mounting Type: Surface Mount Supplier Device Package: Base Product Number:	DG9425EDQ-T1-GE3	Vishay Siliconix
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- Voltage - Supply, Dual (V±): ±3V ~ 8V -3db Bandwidth: - Charge Injection: 38pC Channel Capacitance (CS(off), CD(off)): 49pF, 37pF 1nA Crosstalk: -77dB@1MHz Mounting Type: Surface Mount 16-TSSOP (0.173", 4.40mm Width) Supplier Device Package: Switch Time (Ton, Toff) (Max): Charge Injection: 3V ~ 16V Switch Time (Ton, Toff) (Max): Charge Injection: 38pC Current - Leakage (IS(off)) (Max): 49pF, 37pF 1nA Current - Leakage (IS(off)) (Max): 49pF, 37pF 1nA Coperating Temperature: -40°C ~ 85°C (TA) Mounting Type: Surface Mount 16-TSSOP (0.173", 4.40mm Width) Supplier Device Package: Base Product Number:	4	30hm
Voltage - Supply, Dual (V±): ±3V ~ 8V -3db Bandwidth: - Charge Injection: Channel Capacitance (CS(off), CD(off)): 49pF, 37pF InA Crosstalk: Operating Temperature: -77dB @ 1MHz Mounting Type: Package / Case: Surface Mount Supplier Device Package: Switch Time (Ton, Toff) (Max): Switch Time (Ton, Toff) (Max): 1n, Supplier Device Package: Switch Time (Ton, Toff) (Max): 1n, Supplier Connected (CS(off)) (Max): Charge Injection: Operating Injection: Switch Time (Ton, Toff) (Max): 1n, Supplier Connected (CS(off)) (Max): Charge Injection: Applier Sapc Supplier Device Package: Switch Time (Ton, Toff) (Max): 1n, Supplier Connected (Ton) Suppl	Channel-to-Channel Matching (ΔRon):	Voltage - Supply, Single (V+):
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-3db Bandwidth: Charge Injection: 38pC Channel Capacitance (CS(off), CD(off)): Current - Leakage (IS(off)) (Max): 49pF, 37pF 1nA Crosstalk: Operating Temperature: -77dB @ 1MHz Mounting Type: Package / Case: Surface Mount 16-TSSOP (0.173", 4.40mm Width) Supplier Device Package: Base Product Number:	Voltage - Supply, Dual (V±):	Switch Time (Ton, Toff) (Max):
- Channel Capacitance (CS(off), CD(off)): Current - Leakage (IS(off)) (Max): 49pF, 37pF 1nA Crosstalk: -77dB @ 1MHz Ao°C ~ 85°C (TA) Mounting Type: Package / Case: Surface Mount 16-TSSOP (0.173", 4.40mm Width) Supplier Device Package: Base Product Number:	±3V ~ 8V	51ns, 35ns
Channel Capacitance (CS(off), CD(off)): 49pF, 37pF 1nA Crosstalk: -77dB @ 1MHz Mounting Type: Surface Mount Supplier Device Package: Current - Leakage (IS(off)) (Max): 1nA Operating Temperature: -40°C ~ 85°C (TA) Package / Case: 16-TSSOP (0.173", 4.40mm Width) Base Product Number:	-3db Bandwidth:	Charge Injection:
49pF, 37pF1nACrosstalk:Operating Temperature:-77dB@1MHz-40°C ~ 85°C (TA)Mounting Type:Package / Case:Surface Mount16-TSSOP (0.173", 4.40mm Width)Supplier Device Package:Base Product Number:		38pC
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Surface Mount 16-TSSOP (0.173", 4.40mm Width) Supplier Device Package: Base Product Number:	-77dB @ 1MHz	-40°C ~ 85°C (TA)
Supplier Device Package: Base Product Number:	Mounting Type:	Package / Case:
	Surface Mount	16-TSSOP (0.173", 4.40mm Width)
16-TSSOP DG9425	Supplier Device Package:	Base Product Number:
	16-TSSOP	DG9425

Environmental & Export classification

8542.39.0001

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	

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1.6 Ω On Resistance, \pm 5 V, \pm 12 V, and \pm 3 V Quad SPST Switches

DESCRIPTION

The DG9424E, DG9425E, DG9426E are monolithic quad single-pole-single-throw analog switches. The G9424E and DG9425E differ only in that they respond to opposite logic levels. The DG9426E has two normally open and two normally closed switches. It can be given various configurations, including four SPST, two SPDT, and one DPDT.

Using BiCMOS wafer fabrication technology allows the DG9424E, DG9425E, and DG9426E to operate on single and dual supplies. Single supply voltage ranges from 3 V to 16 V while dual supply operation is recommended with \pm 3 V to \pm 8 V. Each switch conducts equally well in both direction when on, and blocks input voltages up to the supply levels when off.

The low and flat on resistance over the full input signal voltage rang bring excellent linearity, reduce insertion loss and signal distortion, make them ideal for data acquisition and programmable gain control applications. These switch characters also make them ideal fit for audio signal switch and reed relay replacement.

The DG9424E, DG9425E, DG9426E feature low power dissipation, fast switching speed, and low voltage logic control threshold. Proprietary design enables the low charge injection that minimize the switching transient.

Operation temperature is specified from -40 °C to +85 °C. The DG9424E, DG9425E, DG9426E are available in 16 lead TSSOP packages.

FEATURES

- 3 V to 16 V single supply or ± 3 V thru ± 8 V dual supply operation
- 1.6 Ω typical on resistance
- 3 V logic compatible for control
- · Bidirectional rail to rail signal switching
- · Fast switching speed
- < 0.2 nA switch on leakage
- Break-before-make switching DG9426

BENEFITS

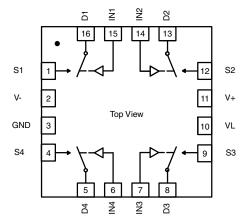
- Wide operation voltage range
- · Low signal errors and distortion
- Fast switching time
- Simple interfacing

APPLICATIONS

- Automatic test equipment
- · Data acquisition systems
- Meters and instruments
- Medical and healthcare systems
- Communication systems
- Audio and video signal routing
- Relay replacement
- Battery powered systems
- Computer peripherals
- Audio and video signal routing

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

QFN-16 (4 mm x 4 mm)



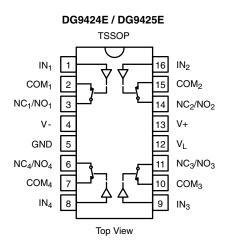
Note

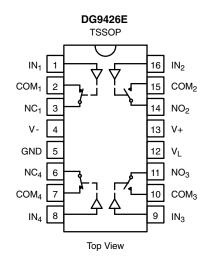
• QFN exposed pad can either be tied to V- or left floating



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FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION





TRUTH TABLE							
LOGIC	DG9424E DG9425E						
0	Off	On					
1	On	Off					

TRUTH TABLE								
LOGIC	SW ₁ , SW ₄	SW ₂ , SW ₃						
0	On	Off						
1	Off	On						

ORDERING IN	ORDERING INFORMATION									
TEMP. RANGE	PACKAGE	PART NUMBER	PART MARKING	STD PACK QUANTITY						
		DG9424EDQ-T1-GE3	9424E	Tape and reel 3000 units						
	16-pin TSSOP	DG9425EDQ-T1-GE3	9425E	Tape and reel 3000 units						
-40 °C to +85 °C		DG9426EDQ-T1-GE3	9426E	Tape and reel 3000 units						
-40 C to +65 C		DG9424EDN-T1-GE4	9424E	Tape and reel 2500 units						
	QFN (4 mm x 4 mm) 16L (variation 2)	DG9425EDN-T1-GE4	9425E	Tape and reel 2500 units						
	(variation 2)	DG9426EDN-T1-GE4	9426E	Tape and reel 2500 units						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		LIMIT	UNIT						
V+ to V-		-0.3 to +18							
GND to V-		18	V						
V _L		(GND - 0.3) to (V+) + 0.3	V						
IN, COM, NC, NO a	M, NC, NO a $(V-) - 0.3$ to $(V+) + 0.3$								
Continuous current (NO, NC, COM p	ins)	100	Λ						
Peak current, S or D (pulsed 1 ms, 10) % duty cycle)	200	mA						
Storage temperature		-65 to +150	°C						
Power dissipation (package) ^b	16 min T000D 0	450	mW						
Thermal resistance b	16-pin TSSOP °	178	°C/W						
ESD human body model (HBM); per	ANSI / ESDA / JEDEC® JS-001	>1500	V						
Latch up current, per JESD78D		400	mA						

Notes

- a. Signals on NC, NO, COM or IN exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings
- b. All leads welded or soldered to PC board
- c. Derate 7 mW/°C above 25 °C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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SPECIFICATIONS a Sing	le Supply 1	2 V						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP. b	-40	UNIT			
		V+ = 12 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V f$		MIN. d	TYP. c	MAX. d		
Analog Switch					ı	,	L	
Analog signal range ^e	V _{ANALOG}		Full	0	-	12	V	
On-resistance	R _{ON}	V+ = 10.8 V, V- = 0 V, $I_{NO}, I_{NC} = 50 \text{ mA}, V_{COM} = 2/9 \text{ V}$	Room	-	1.6	3 4	Ω	
Digital Control							<u> </u>	
Input current	I _{INL} or I _{INH}		Full	-1	0.01	1	μA	
Dynamic Characteristics					L	L		
T 9			Room	-	36	51		
Turn-on time e	t _{ON}	$R_1 = 300 \Omega, C_1 = 35 pF,$	Full	-	-	65		
Turn-off time e	t _{OFF}	V_{NO} , $V_{NC} = 5$ V, see Fig. 2	Room	-	20	35	ns	
rum-on time •			Full	-	-	44	113	
Break-before-make time delay e	t _D	DG9426E only, V_{NO} , V_{NC} = 5 V, R_L = 300 Ω , C_L = 35 pF	Room	2	-	-		
Charge injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	38	-	рС	
Off-isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$,	Room	-	-56	-	dB	
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-77	-	иь	
NO, NC off capacitance e	C _{NO(off)}		Room	-	49	_		
NO, NO on capacitance	C _{NC(off)}	f = 1 MHz	HOOIII	-	49	_	pF	
COM off capacitance e	C _{COM(off)}	I = I IVIDZ	Room	ı	37	-	ρг	
Channel on capacitance ^e	C _{COM(on)}		Room	ı	89	-		
Power Supplies								
Positive supply current	l+		Room	ı	0.02	1		
1 Ositive supply current	IT		Full	-	-	5		
Negative supply current	l-		Room	-1	-0.002	-		
regative supply current	I-	$V_{IN} = 0$ or V_{L}	Full	-5	-	-	μΑ	
Logic supply current	Ι _L	AIN - O OI AF	Room	-	0.002	1	μΛ	
Logio dappiy darront	'L		Full	-	-	5		
Ground current	loup		Room	-1	-0.002	-		
Ground Guiront	I _{GND}		Full	-5	-	-		



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PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	-40	UNIT		
		V+ = 5 V, V- = 5 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	-5		5	V
On-resistance	R _{ON}	V+ = 4.5 V, V- = -4.5 V, $I_{NO}, I_{NC} = 50 \text{ mA}$	Room Full	-	1.9	3.3 4.3	Ω
	I _{NO(off)}		Room	-1	-	1	
O Nobel Miles I and a second	I _{NC(off)}	V+ = 5.5 V, V- = -5.5 V,	Full	-10	-	10	
Switch off leakage current	I _{COM(off)}	$V_{COM} = \pm 4.5 \text{ V}, V_{NO}, V_{NC} = \pm 4.5 \text{ V}$	Room	-1	-	1	nA
			Full	-10	-	10	<u> </u>
Channel on leakage current	I _{COM(on)}	V+ = 5.5 V, V- = -5.5 V,	Room	-1	-	1	
·	O O I VI (O I I)	V_{NO} , $V_{NC} = V_{COM} = \pm 4.5 \text{ V}$	Full	-10	-	10	
Digital Control							1 -
Input current ^a	I _{INL} or I _{INH}		Full	-1	0.05	1	μΑ
Dynamic Characteristics				T		T	T
Turn-on time ^e	t _{ON}		Room	-	48	67	
	-011	$R_L = 300 \Omega, C_L = 35 pF,$	Full	-	-	81	
Turn-off time ^e	t _{OFF}	V_{NO} , $V_{NC} = \pm 3.5$ V, see Fig. 2		-	34	57	ns
	-OFF		Full	-	-	67	
Break-before-make time delay e	t _D	DG9426E only, V_{NO} , V_{NC} = 3.5 V, R_L = 300 Ω , C_L = 35 pF	Room	2	ı	-	
Charge injection ^e	Q_{INJ}	V_g = 0 V, R_g = 0 Ω , C_L = 1 nF	Room	-	112	-	рС
Off isolation e	OIRR	$R_1 = 50 \Omega$, $C_1 = 5 pF$, $f = 1 MHz$	Room	-	-56	-	dB
Channel-to-channel crosstalk e	X _{TALK}	$n_L = 50.52$, $G_L = 5 \text{ pr}$, $I = 1 \text{ Winz}$	Room	-	-82	-	иь
Source off capacitance e	$C_{NO(off)} \ C_{NC(off)}$		Room	-	38	-	_
Drain off capacitance e	C _{COM(off)}	f = 1 MHz	Room	-	38	-	pF
Channel on capacitance e	C _{COM(on)}		Room	-	89	-	
Power Supplies							
Decitive comply comment 6	1.		Room	-	0.03	1	
Positive supply current ^e	I+		Full	-	-	5	
Negative supply surrent 6	,		Room	-1	-0.002	-	
Negative supply current e	I-	V = 0 2*V	Full	-5	-	-	
Logic cumply current 6		$V_{IN} = 0$ or V_L	Room	-	0.002	1	μΑ
Logic supply current e	ΙL		Full	-	-	5	
Crowned assurant 6	_		Room	-1	-0.002	-	
Ground current ^e	I _{GND}		Full	-5	_	_	İ



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SPECIFICATIONS a Singl	e Supply 5 \	V						
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	-40	LIMITS °C to +8	5 °C	UNIT	
		V+ = 5 V, V- = 0 V $V_L = 5 V, V_{IN} = 2.4 V, 0.8 V^f$		MIN. d	TYP. c	MAX. d		
Analog Switch								
Analog signal range e	V _{ANALOG}		Full	-	-	5	V	
On-resistance e	R _{ON}	V+ = 4.5 V, I _{NO} , I _{NC} = 50 mA	Room	-	3.1	4.8	Ω	
On-resistance -	HON	$v+=4.5$ v , i_{NO} , $i_{NC}=30$ mA	Full	-	-	5.8	5.2	
Dynamic Characteristics								
Turn-on time e	t _{ON}		Room	-	62	78		
Turn on time	LON	$R_L = 300 \Omega, C_L = 35 pF,$	Hot	-	-	106		
Turn-off time ^e	t _{OFF}	V_{NO} , $V_{NC} = 3.5 V$, see Fig. 2	Room	-	29	44	ns	
			Hot	-	-	56	110	
Break-before-make time delay ^e	t _D	DG9426E only, V_{NO} , V_{NC} = 3.5 V, R_L = 300 Ω , C_L = 35 pF	Room	5	-	-		
Charge injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	10	-	рС	
Power Supplies								
Dogitive augusty august 6	l+		Room	-	0.02	1		
Positive supply current e	1+		Hot	-	-	5		
Negative cumply current 6	l-		Room	-1	-0.002	-		
Negative supply current e	-	$V_{IN} = 0$ or V_I	Hot	-5	-	-		
Logic supply current e	I.	$\mathbf{v}_{IN} = 0 \; Or \; \mathbf{v}_{L}$	Room	-	0.002	1	μΑ	
Logic supply current -	ال		Hot	-	-	5		
Ground current e	la		Room	-1	-0.002	-		
Ground Current	I _{GND}		Hot	-5	-	-		



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SPECIFICATIONS a Sing	le Supply 3	V					
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED	TEMP.b	-40	LIMITS °C to +8	5 °C	UNIT
		V+ = 3 V, V- = 0 V $V_L = 3 V, V_{IN} = 2.4 V, 0.4 V f$		MIN. d	TYP. c	MAX. d	
Analog Switch							
Analog signal range ^e	V _{ANALOG}		Full	0	-	3	V
On-resistance	R _{ON}	V+ = 2.7 V, V- = 0 V.	Room	ı	6	-	Ω
	HON	I_{NO} , $I_{NC} = 5$ mA, $V_{COM} = 0.5$, 2.2 V	Full	ı	-	-	52
	I _{NO(off)}		Room	-1	-	1	
Switch off leakage current a	I _{NC(off)}	V+ = 3.3 V, V- = 0 V.	Full	-10	-	10	
Switch of leakage current "		$V_{COM} = 0.3, 3 \text{ V}, V_{NO}, V_{NC} = 3, 0.3 \text{ V}$	Room	-1	-	1	nA
	I _{COM(off)}		Full	-10	-	10	nA
Channel on leakage assurent 3		V+ = 3.3 V, V- = 0 V,	Room	-1	-	1	
Channel on leakage current a	I _{COM(on)}	$V_{NO}, V_{NC} = V_{COM} = 0.3, 3 V$	Full	-10	-	10	
Digital Control ^e							
Input current	I _{INL} or I _{INH}		Full	-1	0.005	1	μΑ
Dynamic Characteristics							
Turn-on time	t _{ON}		Room	ı	170	-	
rum-on time	ON	$R_L = 300 \Omega$, $C_L = 35 pF$.	Full	-	-	230	
Turn-off time	t	V_{NO} , $V_{NC} = 1.5 V$, see Fig. 2	Room	ı	65	-	ns
Turn-on time	t _{OFF}		Full	ı	-	89	110
Break-before-make time delay	t _D	DG9426E only, V_{NO} , V_{NC} = 1.5 V, R_L = 300 Ω , C_L = 35 pF	Room	5			
Charge injection ^e	Q _{INJ}	$V_g = 0 \text{ V}, R_g = 0 \Omega, C_L = 1 \text{ nF}$	Room	-	15	-	рС
Off isolation ^e	OIRR	$R_L = 50 \Omega$, $C_L = 5 pF$,	Room	-	-56	-	٦D
Channel-to-channel crosstalk e	X _{TALK}	f = 1 MHz	Room	-	-80	-	dB
Course off conscitones e	C _{NO(off)}		Doom		53		
Source off capacitance e	C _{NC(off)}	f = 1 MHz	Room	-	53	-	nE
Drain off capacitance e	C _{COM(off)}	T = 1 IVIMZ	Room	-	42	-	pF
Channel on capacitance e	C _{COM(on)}		Room	-	92	-	

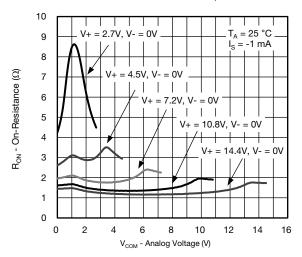
Notes

- a. Leakage parameters are guaranteed by worst case test conditions and not subject to production test
- b. Room = 25 $^{\circ}$ C, Full = As determined by the operating temperature suffix
- c. Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing
- d. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet
- e. Guaranteed by design, not subject to production test
- f. V_{IN} = Input voltage to perform proper function

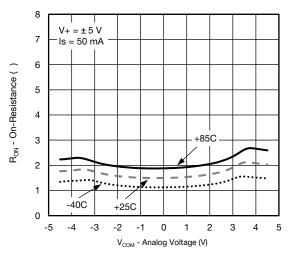


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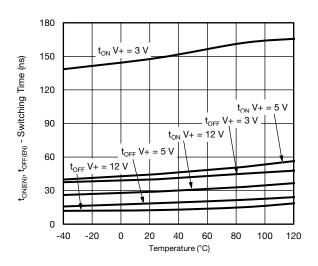
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



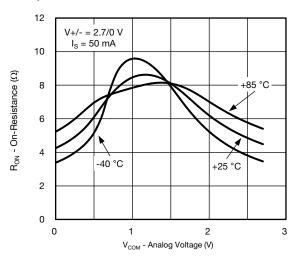
R_{ON} vs. V_{COM} and Supply Voltage



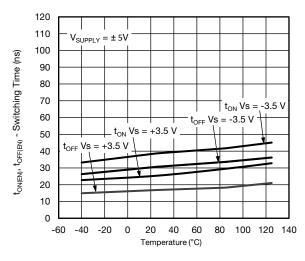
R_{ON} vs. Analog Voltage and Temperature



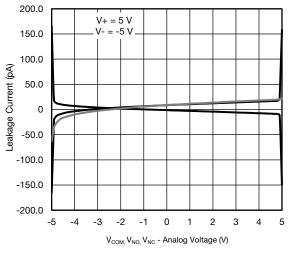
Switching Time vs. Temperature and Single Supply Voltage



R_{ON} vs. Analog Voltage and Temperature



Switching Time vs. Temperature and Dual Supply Voltage

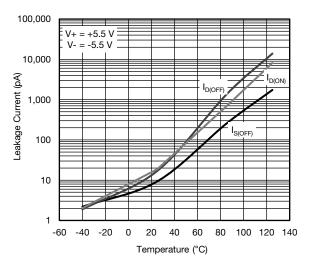


Leakage Current vs. Analog Voltage

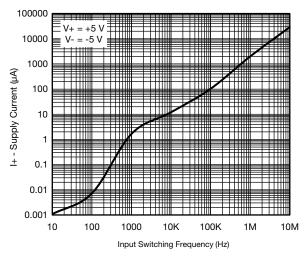


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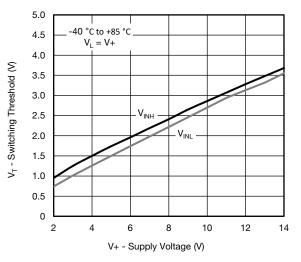
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



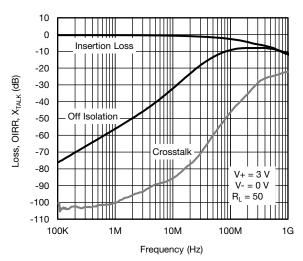
Leakage Current vs. Temperature



Switching Current vs. Input Switching Frequency



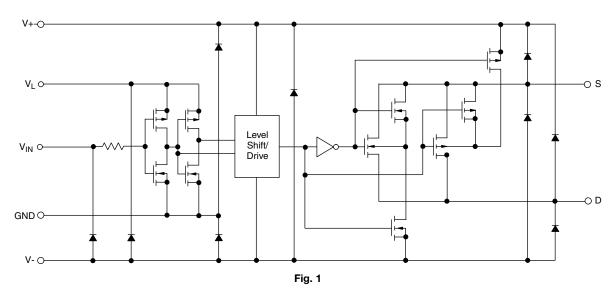
Switching Threshold vs. Supply Voltage



Insertion Loss, Off Isolation and Crosstalk vs. Frequency

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SCHEMATIC DIAGRAM (typical channel)



TEST CIRCUITS

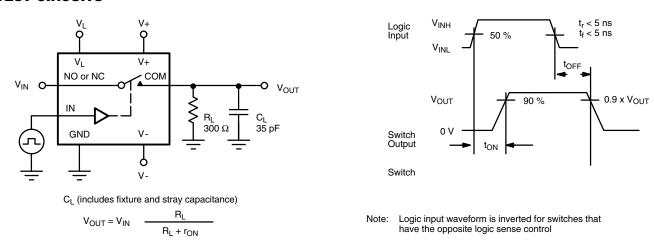


Fig. 2 - Switching Time

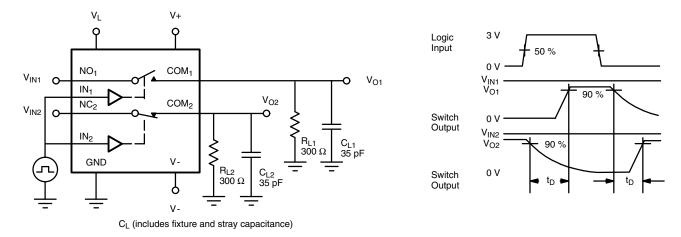
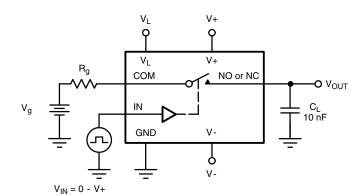
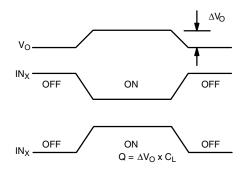


Fig. 3 - Break-Before-Make (DG9426E)

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TEST CIRCUITS





 $\ensuremath{\mathsf{IN}}_X$ dependent on switch configuration Input polarity determined by sense of switch.

Fig. 4 - Charge Injection

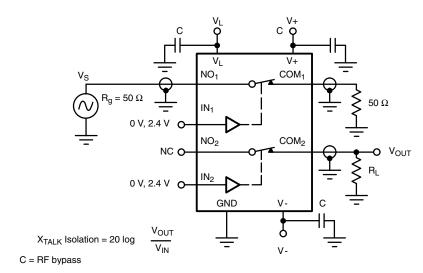


Fig. 5 - Crosstalk

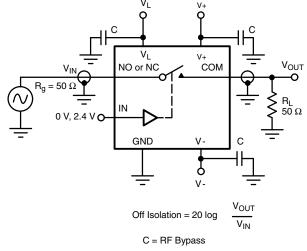


Fig. 6 - Off-Isolation

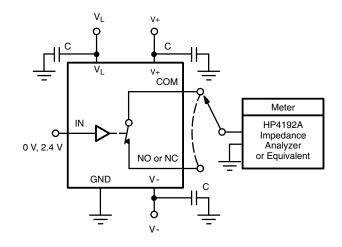


Fig. 7 - Source/Drain Capacitances



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PRODUCT SUMM	MARY					
Part number	DG9424E	DG9424E	DG9425E	DG9425E	DG9426E	DG9426E
Status code	2	2	2	2	2	2
Configuration	SPST x 4, NO	SPST x 4, NO	SPST x 4, NC	SPST x 4, NC	SPST x 4, comp	SPST x 4, comp
Single supply min. (V)	3	3	3	3	3	3
Single supply max. (V)	16	16	16	16	16	16
Dual supply min. (V)	3	3	3	3	3	3
Dual supply max. (V)	8	8	8	8	8	8
On-resistance (Ω)	1.6	1.6	1.6	1.6	1.6	1.6
Charge injection (pC)	38	38	38	38	38	38
Source on capacitance (pF)	89	89	89	89	89	89
Source off capacitance (pF)	37	37	37	37	37	37
Leakage switch on typ. (nA)	-	-	-	-	-	-
Leakage switch off max. (nA)	1	1	1	1	1	1
-3 dB bandwidth (MHz)	-	-	-	-	-	-
Package	TSSOP-16	QFN-16 4 x 4	TSSOP-16	QFN-16 4 x 4	TSSOP-16	QFN-16 4 x 4
Functional circuit / applications	Multi purpose, instrumentation, medical and healthcare, portable					
Interface	Parallel	Parallel	Parallel	Parallel	Parallel	Parallel
Single supply operation	Yes	Yes	Yes	Yes	Yes	Yes
Dual supply operation	Yes	Yes	Yes	Yes	Yes	Yes
Turn on time max. (ns)	51	51	51	51	51	51
Crosstalk and off isolation	-56	-56	-56	-56	-56	-56

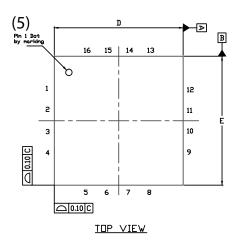
Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?75770.

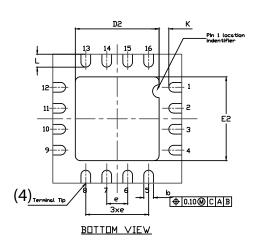


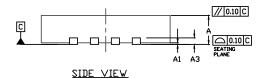
Package Information

Vishay Siliconix

QFN 4x4-16L Case Outline







		VARIATION 1						VARIATION 2					
DIM	МІ	LLIMETERS ⁽¹⁾			INCHES		МІ	MILLIMETERS ⁽¹⁾			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.	
Α	0.75	0.85	0.95	0.029	0.033	0.037	0.75	0.85	0.95	0.029	0.033	0.037	
A1	0	-	0.05	0	-	0.002	0	-	0.05	0	-	0.002	
A3		0.20 ref.	•		0.008 ref.			0.20 ref.			0.008 ref.		
b	0.25	0.30	0.35	0.010	0.012	0.014	0.25	0.30	0.35	0.010	0.012	0.014	
D		4.00 BSC		0.157 BSC		4.00 BSC			0.157 BSC				
D2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106	
е		0.65 BS0)	0.026 BSC			0.65 BSC				0.026 BSC		
Е		4.00 BS0)		0.157 BSC			4.00 BSC			0.157 BSC		
E2	2.0	2.1	2.2	0.079	0.083	0.087	2.5	2.6	2.7	0.098	0.102	0.106	
K		0.20 min.			0.008 min.			0.20 min.			0.008 min.		
L	0.5	0.6	0.7	0.020	0.024	0.028	0.3	0.4	0.5	0.012	0.016	0.020	
N ⁽³⁾	16				16			16		16			
Nd ⁽³⁾		4			4		4				4		
Ne ⁽³⁾		4		4			4			4			

Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

ECN: S13-0893-Rev. B, 22-Apr-13

DWG: 5890

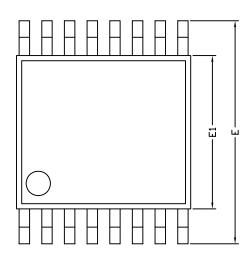
Revision: 22-Apr-13

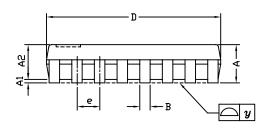


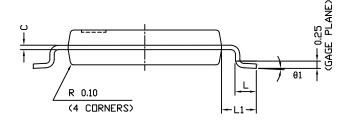
Package Information

Vishay Siliconix

TSSOP: 16-LEAD







Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
Α	-	1.10	1.20
A1	0.05	0.10	0.15
A2	=	1.00	1.05
В	0.22	0.28	0.38
С	=	0.127	=
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
е	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
у	=	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-0	Oct-06		

ECN: S-61920-Rev. D, 23-Oct-06

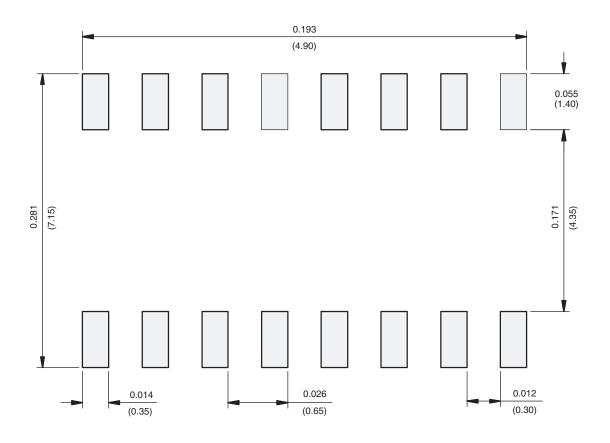
DWG: 5624

Document Number: 74417 23-Oct-06

PAD Pattern

Vishay Siliconix

RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads Dimensions in inches (mm)



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